

HD74LS03

Quadruple 2-Input Positive NAND Gates (with Open Collector Outputs)

REJ03D0390-0200 Rev.2.00 Feb.18.2005

Features

• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LS03P	DILP-14 pin	PRDP0014AB-B (DP-14AV)	Ρ	—
HD74LS03FPEL	SOP-14 pin (JEITA)	PRSP0014DF-B (FP-14DAV)	FP	EL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

Pin Arrangement



Circuit Schematic (1/4)





Absolute Maximum Ratings

ltem	Symbol	Ratings	Unit
Supply voltage	V _{CC} Note	7	V
Input voltage	V _{IN}	7	V
Power dissipation	PT	400	mW
Storage temperature	Tstg	-65 to +150	°C

Note: Voltage value, unless otherwise noted, are with respect to network ground terminal.

Recommended Operating Conditions

Item	Symbol	Min	Тур	Max	Unit
Supply voltage	V _{CC}	4.75	5.00	5.25	V
Output voltage	V _{OH}	—	—	5.5	V
Output current	I _{OL}	—	_	8	mA
Operating temperature	Topr	-20	25	75	°C

Electrical Characteristics

 $(Ta = -20 \text{ to } +75 \ ^{\circ}\text{C})$

Item	Symbol	min.	typ.*	max.	Unit	Condition
Input voltage	V _{IH}	2.0	—		V	
input voltage	V _{IL}		—	0.8	V	
Output voltage	V _{OL}		_	0.5	V	$I_{OL} = 8 \text{ mA}$ $V_{CC} = 4.75 \text{ V}, \text{ V}_{IH} = 2 \text{ V}$
			_	0.4		$I_{OL} = 4 \text{ mA}$
	I _{IH}		_	20	μΑ	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 2.7 \text{ V}$
Input current	IIL		_	-0.4	mA	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 0.4 \text{ V}$
	I,		_	0.1	mA	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 7 \text{ V}$
Output current	I _{ОН}		_	100	μΑ	V_{CC} = 4.75 V, V_{IH} = 0.8 V, V_{OH} = 5.5 V
Supply current	I _{CCH}		0.8	1.6	mA	V _{CC} = 5.25 V
	I _{CCL}	_	2.4	4.4	mA	V _{CC} = 5.25 V
Input clamp voltage	V _{IK}	_	_	-1.5	V	$V_{CC} = 4.75 \text{ V}, \text{ I}_{IN} = -18 \text{ mA}$

Note: $* V_{CC} = 5 V$, Ta = 25°C

Switching Characteristics

 $(V_{CC} = 5 V, Ta = 25^{\circ}C)$

ltem	Symbol	min.	typ.	max.	Unit	Condition
Propagation delay time	t _{PLH}	—	17	32	ns	$C_{1} = 15 \text{ pc} = 0 + 0$
	t _{PHL}	—	25	28	ns	$C_L = 15 \text{ pF}, R_L = 2 \text{ k}\Omega$

Note: Refer to Test Circuit and Waveform of the Common Item "TTL Common Matter (Document No.: REJ27D0005-0100)".



Package Dimensions





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